



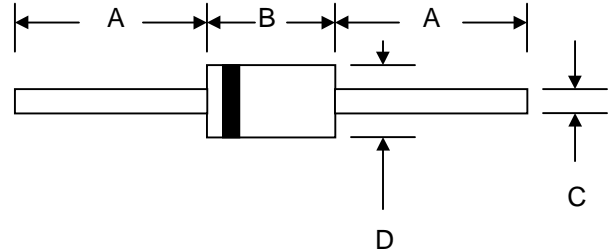
## HER101G – HER108G



### 1.0A GLASS PASSIVATED ULTRAFAST DIODE

#### Features

- Glass Passivated Die Construction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability



#### Mechanical Data

- Case: Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.34 grams (approx.)
- Mounting Position: Any
- Marking: Type Number
- **Lead Free: For RoHS / Lead Free Version,**

DO-41		
Dim	Min	Max
A	25.4	—
B	4.06	5.21
C	0.71	0.864
D	2.00	2.72
All Dimensions in mm		

#### Maximum Ratings and Electrical Characteristics @ $T_A=25^\circ\text{C}$ unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load.  
For capacitive load, derate current by 20%.

Characteristic	Symbol	HER 101G	HER 102G	HER 103G	HER 104G	HER 105G	HER 106G	HER 107G	HER 108G	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$V_{RRM}$ $V_{RWM}$ $V_R$	50	100	200	300	400	600	800	1000	V	
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	140	210	280	420	560	700	V	
Average Rectified Output Current (Note 1) @ $T_A = 55^\circ\text{C}$	$I_O$	1.0								A	
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	60								A	
Forward Voltage @ $I_F = 2.0\text{A}$	$V_{FM}$	1.0			1.3		1.7			V	
Peak Reverse Current @ $T_A = 25^\circ\text{C}$ At Rated DC Blocking Voltage @ $T_A = 100^\circ\text{C}$	$I_{RM}$	5.0					100				$\mu\text{A}$
Reverse Recovery Time (Note 2)	$t_{rr}$	50					75				nS
Typical Junction Capacitance (Note 3)	$C_j$	60					40				pF
Operating Temperature Range	$T_j$	-65 to +150								$^\circ\text{C}$	
Storage Temperature Range	$T_{STG}$	-65 to +150								$^\circ\text{C}$	

#### \*Glass passivated forms are available upon request

- Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case  
2. Measured with  $I_F = 0.5\text{A}$ ,  $I_R = 1.0\text{A}$ ,  $IRR = 0.25\text{A}$ . See figure 5.  
3. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

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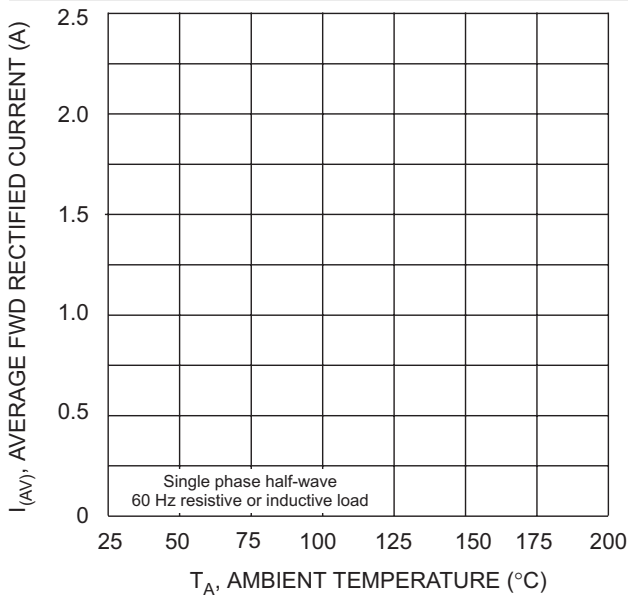


Fig. 1 Forward Current Derating Curve

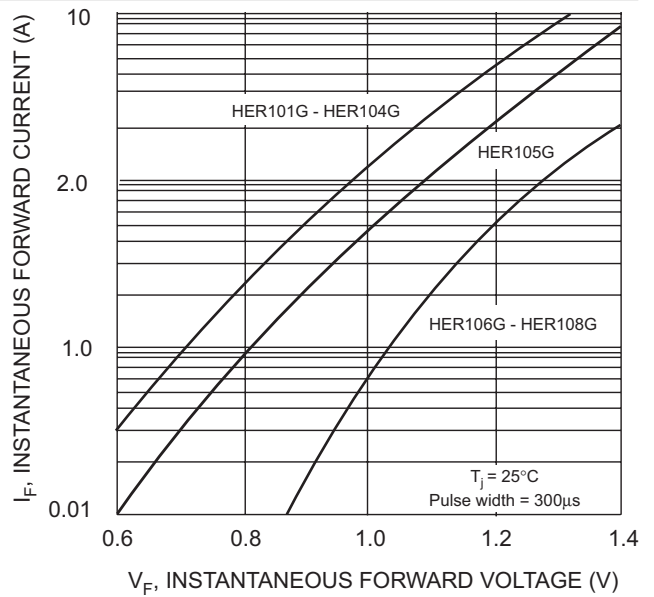


Fig. 2 Typical Forward Characteristics

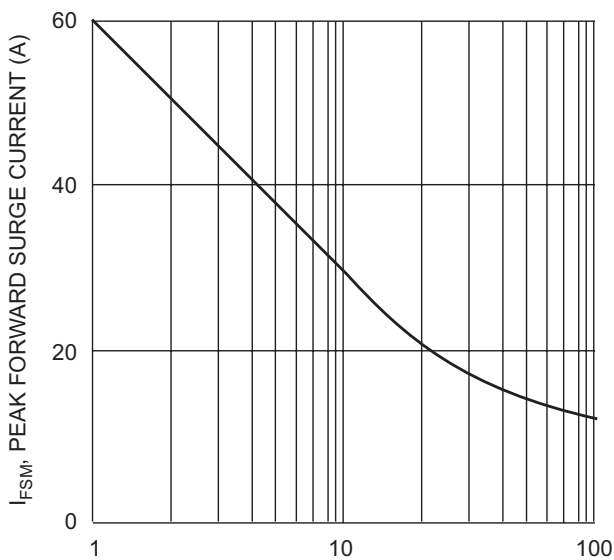


Fig. 3 Peak Forward Surge Current

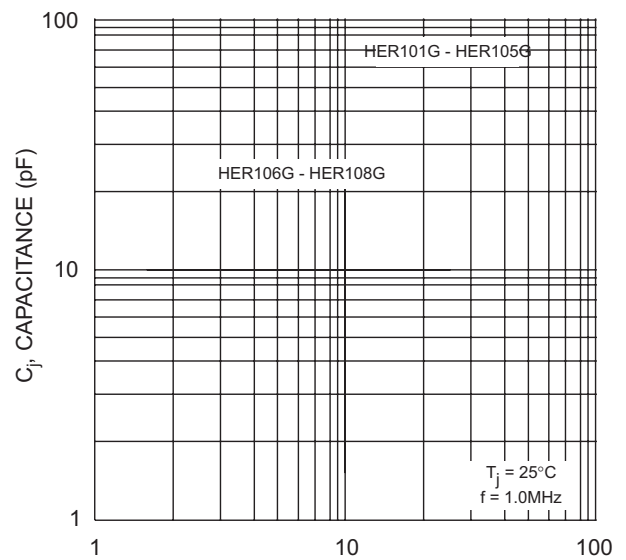
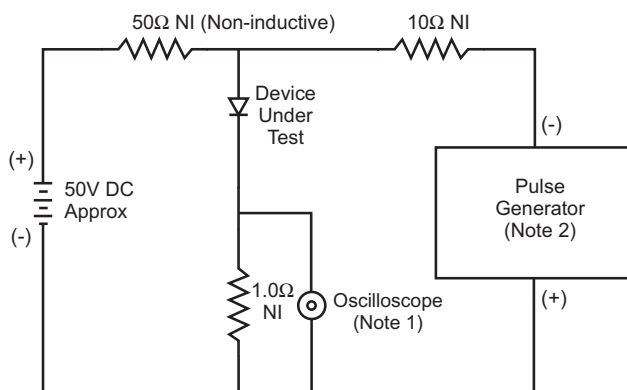
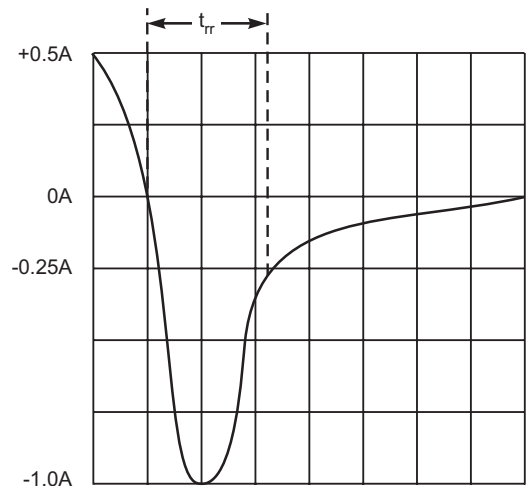


Fig. 4 Typical Junction Capacitance



- Notes:
1. Rise Time = 7.0ns max. Input Impedance = 1.0MΩ, 22pF.
  2. Rise Time = 10ns max. Input Impedance = 50Ω.



Set time base for 5/10ns/cm

Fig. 5 Reverse Recovery Time Characteristic and Test Circuit